

ADC12020

12-Bit, 20 MSPS, 185 mW A/D Converter with Internal Sample-and-Hold

General Description

The ADC12020 is a monolithic CMOS analog-to-digital converter capable of converting analog input signals into 12-bit digital words at 20 Megasamples per second (MSPS), minimum. This converter uses a differential, pipeline architecture with digital error correction and an on-chip sample-and-hold circuit to minimize die size and power consumption while providing excellent dynamic performance. Operating on a single 5V power supply, this device consumes just 185 mW at 20 MSPS, including the reference current. The Power Down feature reduces power consumption to 40 mW.

The differential inputs provide a full scale input swing equal to $2V_{\text{REF}}$ with the possibility of a single-ended input. Full use of the differential input is recommended for optimum performance. For ease of use, the buffered, high impedance, single-ended reference input is converted on-chip to a differential reference for use by the processing circuitry. Output data format is 12-bit offset binary.

This device is available in the 32-lead LQFP package and will operate over the industrial temperature range of -40° C to $+85^{\circ}$ C.

Features

- Internal sample-and-hold
- Outputs 2.5V to 5V compatible
- TTL/CMOS compatible input/outputs
- Power down mode
- On-chip reference buffer

Key Specifications

Resolution 12
Conversion Rate 20 MSPS
DNL ±0.35 LSB
INL ±0.55 LSB
SNR ($f_{IN} = 10.1 \text{ MHz}$) 70 dB

■ ENOB (f_{IN} = 10.1 MHz)■ Data Latency

■ Supply Voltage

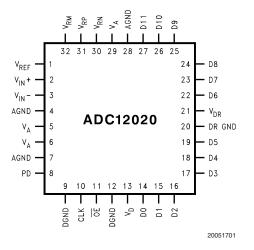
■ Power Consumption, 20 MHz

12 Bits
20 MSPS (min)
£0.35 LSB (typ)
£0.55 LSB (typ)
70 dB (typ)
11.3 bits (typ)
6 Clock Cycles
+5V ±5%
185 mW (typ)

Applications

- Image Processing Front End
- Instrumentation
- PC-Based Data Acquisition
- Fax Machines
- Waveform Digitizers
- Sonar/Radar
- DSP Front Ends

Connection Diagram

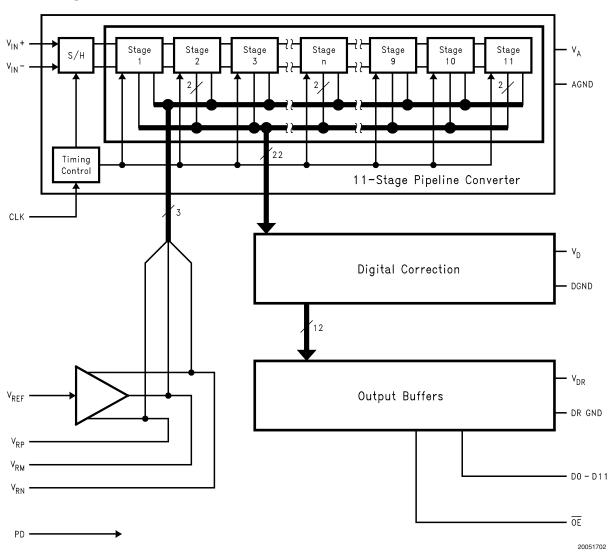


TRI-STATE® is a registered trademark of National Semiconductor Corporation.

Ordering Information

Industrial (–40 $^{\circ}$ C \leq T _A \leq +85 $^{\circ}$ C)	Package
ADC12020CIVY	32 Pin LQFP
ADC12020CIVYX	32 Pin LQFP Tape and Reel
ADC12020EVAL	Evaluation Board

Block Diagram



Pin Descriptions and Equivalent Circuits Pin No. Symbol **Equivalent Circuit** Description **ANALOG I/O** Non-Inverting analog signal Input. With a 2.0V reference 2 voltage, the differential input signal level is 2.0 $V_{\text{P-P}}$ centered V_{IN^+} Inverting analog signal Input. With a 2.0V reference voltage the input signal level is 2.0 $V_{\text{P-P}}$ centered on V_{CM} . This pin 3 V_{IN^-} may be connected to $\ensuremath{V_{\text{CM}}}$ for single-ended operation, but a differential input signal is required for best performance. Reference input. This pin should be bypassed to AGND with a 0.1 μF monolithic capacitor. V_{REF} is 2.0V nominal and V_{REF} should be between 1.0V to 2.2V. V_{RP} 31 These pins are high impedance reference bypass pins. V_{RM} 32 Connect a 0.1 µF capacitor from each of these pins to AGND. DO NOT LOAD these pins. $V_{\rm RN}$ DIGITAL I/O Digital clock input. The range of frequencies for this input is 100 kHz to 30 MHz (typical) with guaranteed performance at CLK 10 20 MHz. The input is sampled on the rising edge of this input. OE is the output enable pin that, when low, enables the TRI-STATE® data output pins. When this pin is high, the ŌĒ 11 outputs are in a high impedance state. PD is the Power Down input pin. When high, this input puts the converter into the power down mode. When this pin is 8 PD low, the converter is in the active mode. DGND

Pin Descriptions and Equivalent Circuits (Continued)

Pin No.	Symbol	Equivalent Circuit	Description			
14–19, 22–27	D0-D11	V _{DR} (D _D)	Digital data output pins that make up the 12-bit conversion results. D0 is the LSB, while D11 is the MSB of the offset binary output word. Output levels are TTL/CMOS compatible.			
ANALOG PO	WER					
5, 6, 29	V _A		Positive analog supply pins. These pins should be connected to a quiet +5V voltage source and bypassed to AGND with 0.1 µF monolithic capacitors located within 1 cm of these power pins, and with a 10 µF capacitor.			
4, 7, 28	AGND		The ground return for the analog supply.			
DIGITAL PO	WER	,	,			
13	V _D		Positive digital supply pin. This pin should be connected to the same quiet +5V source as is V_A and bypassed to DGND with a 0.1 μ F monolithic capacitor in parallel with a 10 μ F capacitor, both located within 1 cm of the power pin.			
9, 12	DGND		The ground return for the digital supply.			
21	V _{DR}		Positive digital supply pin for the ADC12020's output drivers. This pin should be connected to a voltage source of +2.5V to +5V and bypassed to DR GND with a 0.1 μF monolithic capacitor. If the supply for this pin is different from the supply used for V_A and V_D , it should also be bypassed with a 10 μF tantalum capacitor. V_{DR} should never exceed the voltage on V_D . All bypass capacitors should be located within 1 cm of the supply pin.			
20	DR GND		The ground return for the digital supply for the ADC12020's output drivers. This pin should be connected to the system digital ground, but not be connected in close proximity to the ADC12020's DGND or AGND pins. See Section 5 (Layout and Grounding) for more details.			

Absolute Maximum Ratings (Notes 1,

2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

 $\begin{array}{lll} V_{A}, V_{D} & 6.5V \\ V_{DR} & \leq V_{D} + 0.3V \\ |V_{A} - V_{D}| & \leq 100 \text{ mV} \\ \text{Voltage on Any Input or Output Pin} & -0.3V \text{ to } (V_{A} \text{ or } V_{D} \\ & + 0.3V) \\ \text{Input Current at Any Pin (Note 3)} & \pm 25 \text{ mA} \\ \text{Package Input Current (Note 3)} & \pm 50 \text{ mA} \\ \text{Package Dissipation at } T_{A} = 25^{\circ}\text{C} & \text{See (Note 4)} \\ \end{array}$

ESD Susceptibility

Human Body Model (Note 5) 2500V Machine Model (Note 5) 250V

Soldering Temperature, Infrared, 10 sec. (Note 6)

Infrared, 10 sec. (Note 6) 235° C Storage Temperature -65° C to $+150^{\circ}$ C

Operating Ratings (Notes 1, 2)

 $-40^{\circ}C \leq T_{A} \leq +85^{\circ}C$ Operating Temperature Supply Voltage (V_A, V_D) +4.75V to +5.25V Output Driver Supply (V_{DR}) +2.35V to V_D V_{REF} Input 1.0V to 2.4V CLK, PD, OE -0.05V to $(V_D + 0.05V)$ V_{IN} Input -0V to $(V_A - 0.5V)$ 1.0V to 4.0V V_{CM} IAGND-DGNDI ≤100mV

Converter Electrical Characteristics

Unless otherwise specified, the following specifications apply for AGND = DGND = DR GND = 0V, $V_A = V_D = +5V$, $V_{DR} = +3.0V$, PD = 0V, $V_{REF} = +2.0V$, $f_{CLK} = 20$ MHz, $t_r = t_f = 3$ ns, $C_L = 25$ pF/pin. Boldface limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX} : all other limits $T_A = T_J = 25^{\circ}C$ (Notes 7, 8, 9)

Symbol	Parameter	Conditions	Typical (Note 10)	Limits (Note 10)	Units (Limits)				
STATIC (STATIC CONVERTER CHARACTERISTICS								
	Resolution with No Missing Codes			12	Bits (min)				
INL	Integral New Linearity (Nets 11)		+0.55	+1.7	LSB (max)				
IINL	Integral Non Linearity (Note 11)		±0.55	-1.4	LSB (min)				
DNL	Differential Non Linearity		±0.35	+0.9	LSB (max)				
DINL	Differential Nort Linearity		±0.35	-1.0	LSB (min)				
GE	Gain Error		±0.05	2.9	%FS (max)				
	Offset Error (V _{IN} + = V _{IN} -)		-0.04	±1.75	%FS (max)				
	Under Range Output Code		0	0					
	Over Range Output Code		4095	4095					
DYNAMI	CONVERTER CHARACTERISTICS								
FPBW	Full Power Bandwidth	0 dBFS Input, Output at -3 dB	100		MHz				
	Signal-to-Noise Ratio	$f_{IN} = 1 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	70		dB				
SNR		$f_{IN} = 4.4 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	70		dB				
		$f_{IN} = 10.1 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	70	67	dB(min)				
		$f_{IN} = 1 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	70		dB				
SINAD	Signal-to-Noise and Distortion	$f_{IN} = 4.4 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	70		dB				
		$f_{IN} = 10.1 MHz, V_{IN} = -0.5 dBFS$	69	67	dB (min)				
		$f_{IN} = 1 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	11.3		dB				
ENOB	Effective Number of Bits	$f_{IN} = 4.4 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	11.3		dB				
		$f_{IN} = 10.1 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	11.3	10.8	dB(min)				
		$f_{IN} = 1 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	-83		dB				
TUD	Total Hammania Distantian	$f_{IN} = 4.4 \text{ MHz}, V_{IN} = -0.5 \text{ dBFS}$	-83		dB				
THD	Total Harmonic Distortion	$f_{IN} = 10.1 \text{ MHz}, +25^{\circ}\text{C}$	-83	-74	dB (min)				
		$V_{IN} = -0.5 \text{ dBFS}$ +85°C		-71	dB (min)				

Converter Electrical Characteristics (Continued)

Unless otherwise specified, the following specifications apply for AGND = DGND = DR GND = 0V, $V_A = V_D = +5V$, $V_{DR} = +3.0V$, PD = 0V, $V_{REF} = +2.0V$, $f_{CLK} = 20$ MHz, $t_r = t_f = 3$ ns, $C_L = 25$ pF/pin. **Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}:** all other limits $T_A = T_J = 25^{\circ}C$ (Notes 7, 8, 9)

Symbol	Parameter	Conditions		Typical (Note 10)	Limits (Note 10)	Units (Limits)
		$f_{IN} = 1 \text{ MHz}, V_{IN} = -0.5$	dBFS	86		dB
SFDR	Spurious Free Dynamic Range	$f_{IN} = 4.4 \text{ MHz}, V_{IN} = -0$.5 dBFS	86		dB
SFUR	Spundus Free Dynamic Hange	f _{IN} = 10.1 MHz,	+25°C	86	71	dB(min)
		$V_{IN} = -0.5 \text{ dBFS}$	+85°C		68	dB(min)
IMD	Intermodulation Distortion	f _{IN} = 4.7 MHz and 5.3 MHz, each = -7 dBFS		-73		dBFS
REFERE	NCE AND ANALOG INPUT CHARAC	TERISTICS				
V _{CM}	Common Mode Input Voltage			V _A /2		V
	V _{IN} Input Capacitance (each pin to	V _{IN} = 2.5 Vdc	(CLK LOW)	8		pF
C _{IN}	GND)	+ 0.7 V _{rms}	(CLK HIGH)	7		pF
V	Deference Voltage (Note 12)			2.00	1.0	V (min)
V_{REF}	Reference Voltage (Note 13)			2.00	2.4	V (max)
	Reference Input Resistance			100		MΩ(min)

DC and Logic Electrical Characteristics

Unless otherwise specified, the following specifications apply for AGND = DGND = DR GND = 0V, $V_A = V_D = +5V$, $V_{DR} = +3.0V$, PD = 0V, $V_{REF} = +2.0V$, $f_{CLK} = 20$ MHz, $t_r = t_f = 3$ ns, $C_L = 25$ pF/pin. **Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}:** all other limits $T_A = T_J = 25^{\circ}C$ (Notes 7, 8, 9)

Symbol	Parameter	Conditions		Typical (Note 10)	Limits (Note 10)	Units (Limits)			
CLK, PD.	LK, PD, OE DIGITAL INPUT CHARACTERISTICS								
V _{IN(1)}									
V _{IN(0)}	Logical "0" Input Voltage	$V_D = 4.75V$			1.0	V (max)			
I _{IN(1)}	Logical "1" Input Current	V _{IN} = 5.0V		10		μA			
I _{IN(0)}	Logical "0" Input Current	V _{IN} = 0V		-10		μA			
C _{IN}	Digital Input Capacitance			5		pF			
D0-D11	DIGITAL OUTPUT CHARACTERISTI	CS							
	1: 1 "4" Ot	0.5	$V_{DR} = 2.5V$		2.3	V (min)			
$V_{OUT(1)}$	Logical "1" Output Voltage	$I_{OUT} = -0.5 \text{ mA}$	$V_{DR} = 3V$		2.7	V (min)			
V _{OUT(0)}	Logical "0" Output Voltage	I _{OUT} = 1.6 mA, V _{DR} =	3V		0.4	V (max)			
_	TDI OTATE Outsit Oursell	$V_{OUT} = 2.5V \text{ or } 5V$ $V_{OUT} = 0V$		100		nA			
l _{OZ}	TRI-STATE Output Current			-100		nA			
+l _{SC}	Output Short Circuit Source Current	V _{OUT} = 0V		-20		mA (min)			
-I _{SC}	Output Short Circuit Sink Current	$V_{OUT} = V_{DR}$		20		mA (min)			
POWER	SUPPLY CHARACTERISTICS	1							
I _A	Analog Supply Current	PD Pin = DGND, V _{REF} PD Pin = V _{DR}	= 2.0V	32.3 8	41	mA(max) mA			
I _D	Digital Supply Current	PD Pin = DGND PD Pin = V _{DB} , f _{CLK} = 0		3.3 3.5	4.5	mA (max) mA			
I _{DR}	Digital Output Supply Current	PD Pin = DGND, $C_L = 0$ pF (Note 14) PD Pin = V_{DR} , $f_{CLK} = 0$		3 0		mA (max) mA			
	Total Power Consumption	PD Pin = DGND, $C_L = 0$ pF (Note 15) PD Pin = V_{DR} , $f_{CLK} = 0$		178 40	227	mW mW			
PSRR1+	Power Supply Rejection Ratio	Rejection of Positive Full-Scale Error with $V_A = 4.75V$ to 5.25V		69		dBFS			

DC and Logic Electrical Characteristics (Continued)

Unless otherwise specified, the following specifications apply for AGND = DGND = DR GND = 0V, $V_A = V_D = +5V$, $V_{DR} = +3.0V$, PD = 0V, $V_{REF} = +2.0V$, $f_{CLK} = 20$ MHz, $t_r = t_f = 3$ ns, $C_L = 25$ pF/pin. **Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}:** all other limits $T_A = T_J = 25^{\circ}C$ (Notes 7, 8, 9)

Symbol	Parameter	Conditions	Typical (Note 10)	Limits (Note 10)	Units (Limits)
PSRR1-	Power Supply Rejection Ratio	Rejection of Positive Full-Scale Error with $V_A = 4.75V$ to 5.25V	51		dBFS
PSRR2	Power Supply Rejection Ratio	Rejection of Power Supply Noise with 10 MHz, 250 mV _{P-P} riding on V _A	48		dBFS

AC Electrical Characteristics

Unless otherwise specified, the following specifications apply for AGND = DGND = DR GND = 0V, $V_A = V_D = +5V$, $V_{DR} = +3.0V$, PD = 0V, $V_{REF} = +2.0V$, $f_{CLK} = 20$ MHz, $t_r = t_f = 3$ ns, $C_L = 25$ pF/pin. **Boldface limits apply for T_A = T_J = T_{MIN} to T_{MAX}:** all other limits $T_A = T_J = 25^{\circ}C$ (Notes 7, 8, 9, 12)

Symbol	Parameter	Conditions	Typical (Note 10)	Limits (Note 10)	Units (Limits)
f _{CLK} 1	Maximum Clock Frequency		20	30	MHz (min)
f _{CLK} ²	Minimum Clock Frequency		100		kHz
t _{CH}	Clock High Time			20	ns(min)
t _{CL}	Clock Low Time			20	ns(min)
+	Conversion Latency			6	Clock
t _{CONV}					Cycles
+	Data Output Delay after Rising	$V_{DR} = 2.5V$	11	16.8	ns(max)
t _{OD}	CLK Edge	$V_{DR} = 3.0V$	11	16.8	ns(max)
t _{AD}	Aperture Delay		1.2		ns
t _{AJ}	Aperture Jitter		2		ps rms
+	Data outputs into TRI-STATE		4		
t _{DIS}	Mode		4		ns
+	Data Outputs Active after		4		ns
t _{EN}	TRI-STATE				115
t_{PD}	Power Down Mode Exit Cycle	0.1µF capacitor on pins 30, 31, 32	500		ns

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: All voltages are measured with respect to GND = AGND = DGND = 0V, unless otherwise specified.

Note 3: When the input voltage at any pin exceeds the power supplies (that is, V_{IN} < AGND, or V_{IN} > V_A), the current at that pin should be limited to 25 mA. The 50 mA maximum package input current rating limits the number of pins that can safely exceed the power supplies with an input current of 25 mA to two.

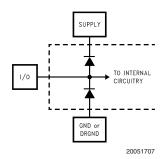
Note 4: The absolute maximum junction temperature $(T_J max)$ for this device is 150°C. The maximum allowable power dissipation is dictated by $T_J max$, the junction-to-ambient thermal resistance (θ_{JA}) , and the ambient temperature, (T_A) , and can be calculated using the formula $P_D MAX = (T_J max - T_A)/\theta_{JA}$. In the 32-pin LQFP, θ_{JA} is 79°C/W, so $P_D MAX = 1,582$ mW at 25°C and 823 mW at the maximum operating ambient temperature of 85°C. Note that the power consumption of this device under normal operation will typically be about 205 mW (185 typical power consumption + 20 mW TTL output loading). The values for maximum power dissipation listed above will be reached only when the device is operated in a severe fault condition (e.g. when input or output pins are driven beyond the power supply voltages, or the power supply polarity is reversed). Obviously, such conditions should always be avoided.

Note 5: Human body model is 100 pF capacitor discharged through a 1.5 k Ω resistor. Machine model is 220 pF discharged through 0Ω .

Note 6: The 235°C reflow temperature refers to infrared reflow. For Vapor Phase Reflow (VPR), the following Conditions apply: Maintain the temperature at the top of the package body above 183°C for a minimum 60 seconds. The temperature measured on the package body must not exceed 220°C. Only one excursion above 183°C is allowed per reflow cycle.

Note 7: The inputs are protected as shown below. Input voltage magnitudes above V_A or below GND will not damage this device, provided current is limited per (Note 3). However, errors in the A/D conversion can occur if the input goes above V_A or below GND by more than 100 mV. As an example, if V_A is 4.75V, the full-scale input voltage must be \leq 4.85V to ensure accurate conversions.

AC Electrical Characteristics (Continued)



- Note 8: To guarantee accuracy, it is required that $|V_A V_D| \le 100 \text{ mV}$ and separate bypass capacitors are used at each power supply pin.
- Note 9: With the test condition for V_{REF} = +2.0V (4 V_{P-P} differential input), the 12-bit LSB is 977 μ V.
- Note 10: Typical figures are at T_A = T_J = 25°C, and represent most likely parametric norms. Test limits are guaranteed to National's AOQL (Average Outgoing Quality Level)
- Note 11: Integral Non Linearity is defined as the deviation of the analog value, expressed in LSBs, from the straight line that passes through positive and negative full-scale.
- Note 12: Timing specifications are tested at TTL logic levels, $V_{IL} = 0.4V$ for a falling edge and $V_{IH} = 2.4V$ for a rising edge.
- Note 13: Optimum performance will be obtained by keeping the reference input in the 1.8V to 2.2V range. The LM4051CIM3-ADJ (SOT-23 package) is recommended for this application.
- Note 14: I_{DR} is the current consumed by the switching of the output drivers and is primarily determined by load capacitance on the output pins, the supply voltage, V_{DR} , and the rate at which the outputs are switching (which is signal dependent). $I_{DR} = V_{DR}(C_0 \times f_0 + C_1 \times f_1 + ... + C_{11} \times f_{11})$ where V_{DR} is the output driver power supply voltage, C_0 is total capacitance on the output pin, and f_0 is the average frequency at which that pin is toggling.
- Note 15: Excludes I_{DR} . See note 14.

Specification Definitions

APERTURE DELAY is the time after the rising edge of the clock to when the input signal is acquired or held for conversion.

APERTURE JITTER (APERTURE UNCERTAINTY) is the variation in aperture delay from sample to sample. Aperture jitter manifests itself as noise in the output.

CLOCK DUTY CYCLE is the ratio of the time during one cycle that a repetitive digital waveform is high to the total time of one period. The specification here refers to the ADC clock input signal.

COMMON MODE VOLTAGE (V_{CM}) is the d.c. potential present at both signal inputs to the ADC.

CONVERSION LATENCY See PIPELINE DELAY.

DIFFERENTIAL NON-LINEARITY (DNL) is the measure of the maximum deviation from the ideal step size of 1 LSB.

EFFECTIVE NUMBER OF BITS (ENOB, or EFFECTIVE BITS) is another method of specifying Signal-to-Noise and Distortion or SINAD. ENOB is defined as (SINAD - 1.76) / 6.02 and says that the converter is equivalent to a perfect ADC of this (ENOB) number of bits.

FULL POWER BANDWIDTH is a measure of the frequency at which the reconstructed output fundamental drops 3 dB below its low frequency value for a full scale input.

GAIN ERROR is the deviation from the ideal slope of the transfer function. It can be calculated as:

Gain Error = Positive Full Scale Error - Offset Error

INTEGRAL NON LINEARITY (INL) is a measure of the deviation of each individual code from a line drawn from negative full scale (½ LSB below the first code transition) through positive full scale (½ LSB above the last code transition). The deviation of any given code from this straight line is measured from the center of that code value.

INTERMODULATION DISTORTION (IMD) is the creation of additional spectral components as a result of two sinusoidal frequencies being applied to the ADC input at the same time. It is defined as the ratio of the power in the intermodulation products to the total power in the original frequencies. IMD is usually expressed in dBFS.

MISSING CODES are those output codes that will never appear at the ADC outputs. The ADC12020 is guaranteed not to have any missing codes.

NEGATIVE FULL SCALE ERROR is the difference between the actual first code transition and its ideal value of ½ LSB above negative full scale.

OFFSET ERROR is the difference between the two input voltages ($V_{\rm IN}$ + $-V_{\rm IN}$ -) required to cause a transition from code 2047 to 2048.

OUTPUT DELAY is the time delay after the rising edge of the clock before the data update is presented at the output pins.

PIPELINE DELAY (LATENCY) is the number of clock cycles between initiation of conversion and when that data is presented to the output driver stage. Data for any given sample is available at the output pins the Pipeline Delay plus the Output Delay after the sample is taken. New data is available at every clock cycle, but the data lags the conversion by the pipeline delay.

POSITIVE FULL SCALE ERROR is the difference between the actual last code transition and its ideal value of 1½ LSB below positive full scale.

POWER SUPPLY REJECTION RATIO (PSRR) is a measure of how well the ADC rejects a change in the power supply voltage. For the ADC12020, PSRR1 is the ratio of the change in Full-Scale Error that results from a change in the dc power supply voltage, expressed in dB. PSRR2 is a measure of how well an a.c. signal riding upon the power supply is rejected at the output.

SIGNAL TO NOISE RATIO (SNR) is the ratio, expressed in dB, of the rms value of the input signal to the rms value of the sum of all other spectral components below one-half the sampling frequency, not including harmonics or dc.

SIGNAL TO NOISE PLUS DISTORTION (S/N+D or SINAD) Is the ratio, expressed in dB, of the rms value of the input signal to the rms value of all of the other spectral components below half the clock frequency, including harmonics but excluding dc.

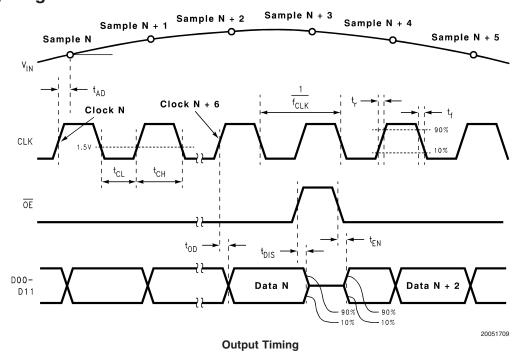
SPURIOUS FREE DYNAMIC RANGE (SFDR) is the difference, expressed in dB, between the rms values of the input signal and the peak spurious signal, where a spurious signal is any signal present in the output spectrum that is not present at the input.

TOTAL HARMONIC DISTORTION (THD) is the ratio, expressed in dBc, of the rms total of the first nine harmonic levels at the output to the level of the fundamental at the output. THD is calculated as

THD = 20 x log
$$\sqrt{\frac{f_2^2 + \dots + f_{10}^2}{f_1^2}}$$

where f_1 is the RMS power of the fundamental (output) frequency and f_2 through f_{10} are the RMS power in the first 9 harmonic frequencies.

Timing Diagram



Transfer Characteristic

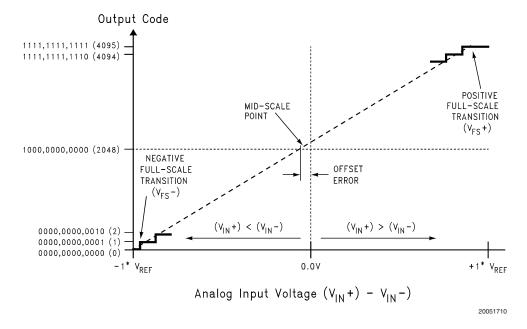
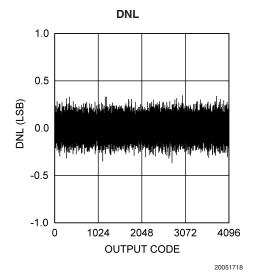
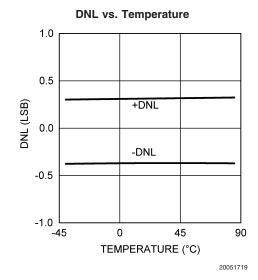
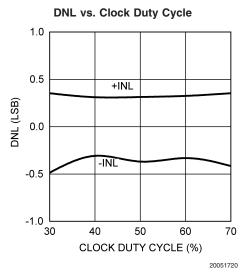
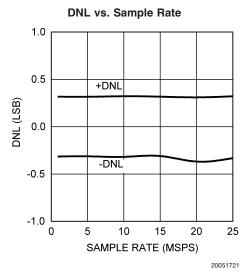


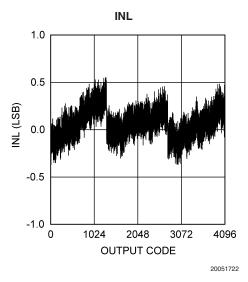
FIGURE 1. Transfer Characteristic

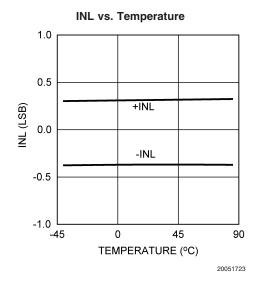


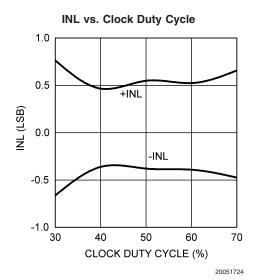


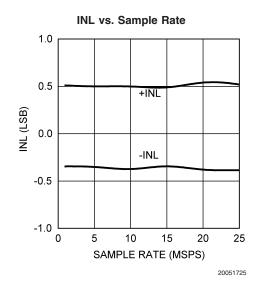


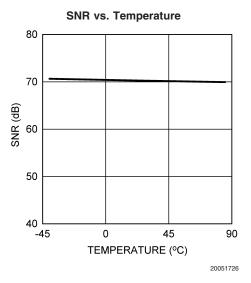


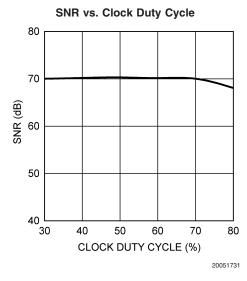


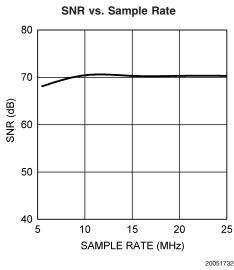


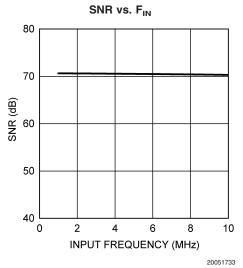


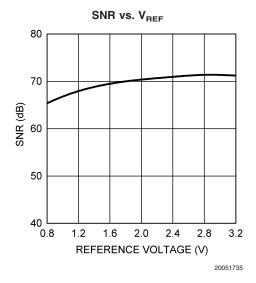


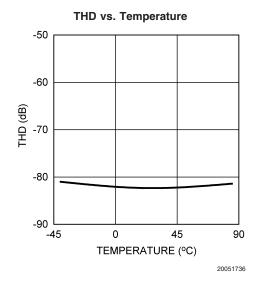


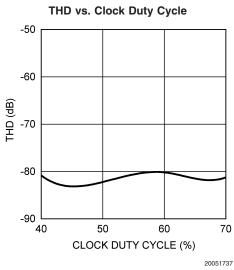


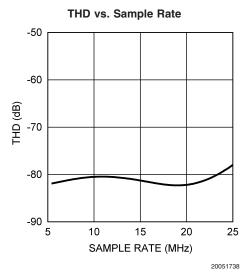


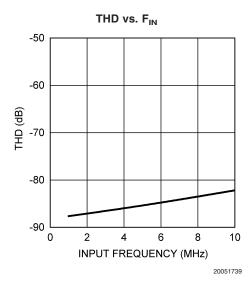


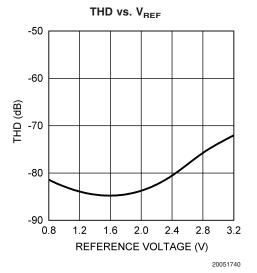




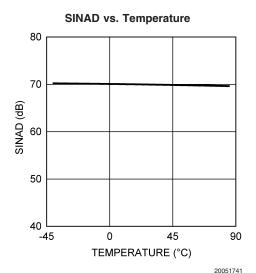


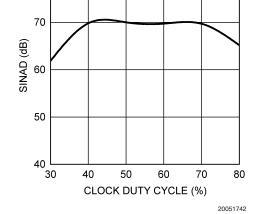




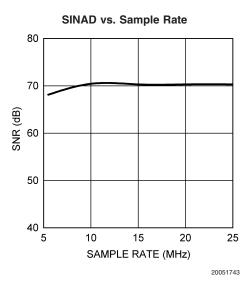


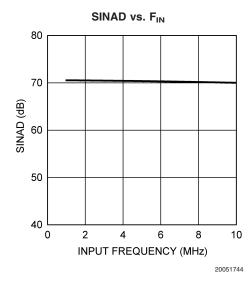
80

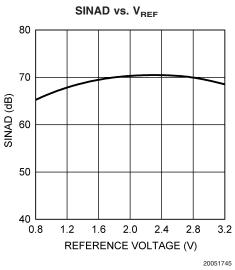


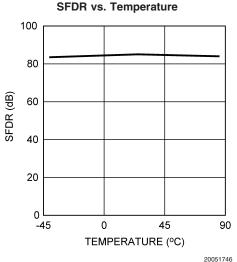


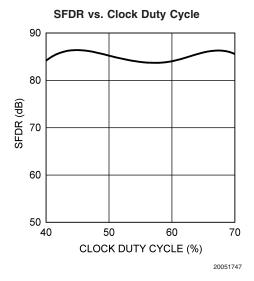
SINAD vs. Clock Duty Cycle

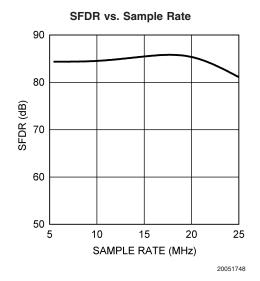


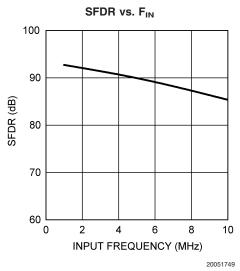


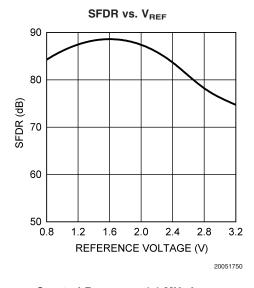


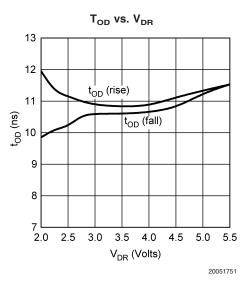


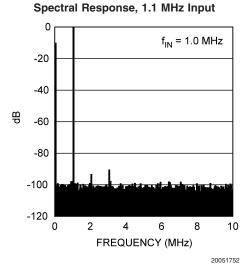




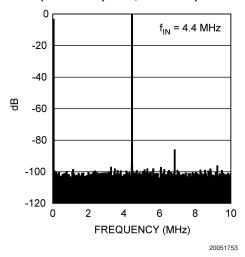




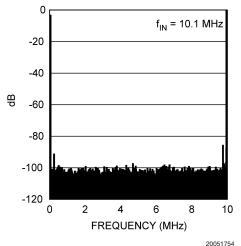




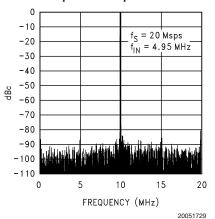
Spectral Response, 44 MHz Input



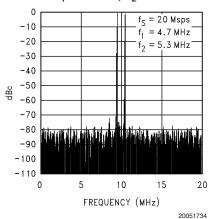
Spectral Response, 10.1 MHz Input



Spectral Response



IMD @ $F_1 = 9.5MHz$, $F_2 = 10.5MHz$



Functional Description

Operating on a single +5V supply, the ADC12020 uses a pipeline architecture and has error correction circuitry to help ensure maximum performance. The differential analog input signal is digitized to 12 bits.

The reference input is buffered to ease the task of driving that pin.

The output word rate is the same as the clock frequency, which can be between 100 kSPS and 30 MSPS (typical). The analog input voltage is acquired at the rising edge of the clock and the digital data for a given sample is delayed by the pipeline for 6 clock cycles.

A logic high on the power down (PD) pin reduces the converter power consumption to 40 mW.

Applications Information

1.0 OPERATING CONDITIONS

We recommend that the following conditions be observed for operation of the ADC12020:

$$\begin{split} 4.75\text{V} &\leq \text{V}_{\text{A}} \leq 5.25\text{V} \\ \text{V}_{\text{D}} &= \text{V}_{\text{A}} \\ 2.35\text{V} &\leq \text{V}_{\text{DR}} \leq \text{V}_{\text{D}} \\ 100 \text{ kHz} &\leq \text{f}_{\text{CLK}} \leq 30 \text{ MHz} \\ 1.0\text{V} &\leq \text{V}_{\text{REF}} \leq 2.4\text{V} \end{split}$$

1.1 Analog Inputs

The ADC12020 has two analog signal inputs, V_{IN} + and V_{IN} -. These two pins form a differential input pair. There is one reference input pin, V_{BEF} .

1.2 Reference Pins

The ADC12020 is designed to operate with a 2.0V reference, but performs well with reference voltages in the range of 1.0V to 2.4V. Lower reference voltages will decrease the signal-to-noise ratio (SNR) of the ADC12020. Increasing the reference voltage (and the input signal swing) beyond 2.4V will degrade THD for a full-scale input. It is very important that all grounds associated with the reference voltage and the input signal make connection to the analog ground plane at a single point to minimize the effects of noise currents in the ground path.

The three Reference Bypass Pins (V_{RP} , V_{RM} and V_{RN}) are made available for bypass purposes. These pins should each be bypassed to ground with a 0.1 μ F capacitor. Smaller capacitor values will allow faster recovery from the power down mode, but may result in degraded noise performance. DO NOT LOAD these pins.

1.3 Signal Inputs

The signal inputs are $V_{\text{IN}}+$ and $V_{\text{IN}}-$. The input signal, V_{IN} , is defined as

$$V_{IN} = (V_{IN} +) - (V_{IN} -)$$

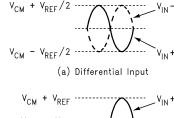
Figure 2 shows the expected input signal range.

Note that the common mode input voltage range is 1V to 3V with a nominal value of $V_{\rm A}/2$. The input signals should remain between ground and 4V.

The Peaks of the individual input signals ($V_{IN}+$ and $V_{IN}-$) should each never exceed the voltage described as

$$V_{IN}+$$
, $V_{IN}-=V_{REF}+V_{CM}$

to maintain THD and SINAD performance.



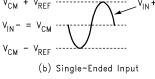


FIGURE 2. Expected Input Signal Range

The ADC12020 performs best with a differential input with each input centered around $V_{\rm CM}.$ The peak-to-peak voltage swing at both $V_{\rm IN}+$ and $V_{\rm IN}-$ EACH should not exceed the value of the reference voltage or the output data will be clipped. The two input signals should be exactly 180° out of phase from each other and of the same amplitude. For single frequency inputs, angular errors result in a reduction of the effective full scale input. For a complex waveform, however, angular errors will result in distortion.

For angular deviations of up to 10 degrees from these two signals being 180 out of phase, the full scale error in LSB can be described as approximately

$$E_{FS} = dev^{1.79}$$

Where dev is the angular difference, in degrees, between the two signals having a 180° relative phase relationship to each other (see *Figure 3*). Drive the analog inputs with a source impedance less than 100Ω .

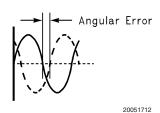


FIGURE 3. Angular Errors Between the Two Input Signals Will Reduce the Output Level

For differential operation, each analog input signal should have a peak-to-peak voltage equal to the input reference voltage, $V_{\rm REF}$, and be centered around a common mode voltage, $V_{\rm CM}$.

TABLE 1. Input to Output Relationship— Differential Input

V _{IN} +	V _{IN} -	Output
V _{CM} - V _{REF} /2	$V_{CM} + V_{REF}/2$	0000 0000 0000
V _{CM} - V _{REF} /4	$V_{CM} + V_{REF}/4$	0100 0000 0000
V _{CM}	V _{CM}	1000 0000 0000
V _{CM} + V _{REF} /4	V _{CM} - V _{REF} /4	1100 0000 0000
V _{CM} + V _{REF} /2	V _{CM} - V _{REF} /2	1111 1111 1111

TABLE 2. Input to Output Relationship— Single-Ended Input

V _{IN} +	V _{IN} -	Output
V _{CM} - V _{REF}	V _{CM}	0000 0000 0000
V _{CM} – V _{REF} /2	V _{CM}	0100 0000 0000
V _{CM}	V _{CM}	1000 0000 0000
V _{CM} + V _{REF} /2	V _{CM}	1100 0000 0000
V _{CM} + V _{REF}	V _{CM}	1111 1111 1111

1.3.1 Single-Ended Operation

Single-ended performance is lower than with differential input signals. For this reason, single-ended operation is not recommended. However, if single ended-operation is required, one of the analog inputs should be connected to the d.c. common mode voltage of the driven input. The peak-to-peak differential input signal should be twice the reference voltage to maximize SNR and SINAD performance (Figure 2b).

For example, set V_{REF} to 1.0V, bias V_{IN} – to 1.0V and drive V_{IN} + with a signal range of 0V to 2.0V. Because very large input signal swings can degrade distortion performance, better performance with a single-ended input can be obtained by reducing the reference voltage when maintaining a full-range output. *Table 1* and *Table 2* indicate the input to output relationship of the ADC12020.

1.3.2 Driving the Analog Inputs

The $V_{\rm IN}+$ and the $V_{\rm IN}-$ inputs of the ADC12020 consist of an analog switch followed by a switched-capacitor amplifier. The capacitance seen at the analog input pins changes with the clock level, appearing as 8 pF when the clock is low, and 7 pF when the clock is high. Although this difference is small, a dynamic capacitance is more difficult to drive than is a fixed capacitance, so choose the driving amplifier carefully. The LMH6702 and the LM6628 are good amplifiers for driving the ADC12020.

The internal switching action at the analog inputs causes energy to be output from the input pins. As the driving source tries to compensate for this, it adds noise to the signal. To prevent this, use 100Ω series resistors at each of the signal inputs with a 75 pF at each of the inputs, as can be seen in Figure 5 and Figure 6. These components should be placed close to the ADC because the input pins of the ADC is the most sensitive part of the system and this is the last opportunity to filter the input. Table 3 gives component values for Figure 5 to convert input signals to a range or 2.5V $\pm 2.0V$ at each of the differential input pins of the ADC12010.

TABLE 3. Resistor values for Circuit of Figure 5

SIGNAL RANGE	R1	R2	R3	R4	R5, R6
0 - 0.5V	392Ω	1540Ω	102Ω	115Ω	1000Ω
0 - 1.0V	634Ω	1470Ω	2490Ω	1050Ω	499Ω
±0.25V	499Ω	499Ω	499Ω	499Ω	1000Ω
±0.5V	100Ω	200Ω	100Ω	200Ω	499Ω

1.3.3 Input Common Mode Voltage

The input common mode voltage, V_{CM} , should be in the range of 0.5V to 4.0V and be of a value such that the peak excursions of the analog signal does not go more negative than ground or more positive than 1.2 Volts below the V_A supply voltage. The nominal V_{CM} should generally be equal to $V_{REF}/2$, but V_{RM} can be used as a V_{CM} source as long as V_{CM} need not supply more than 10 μA of current.

2.0 DIGITAL INPUTS

The digital TTL/CMOS compatible inputs consist of CLK, $\overline{\text{OE}}$ and PD.

2.1 CLK

The **CLK** signal controls the timing of the sampling process. Drive the clock input with a stable, low jitter clock signal in the range of 100 kHz to 30 MHz with rise and fall times of less than 3ns. The trace carrying the clock signal should be as short as possible and should not cross any other signal line, analog or digital, not even at 90°.

If the **CLK** is interrupted, or its frequency too low, the charge on internal capacitors can dissipate to the point where the accuracy of the output data will degrade. This is what limits the lowest sample rate to 100 kSPS.

The duty cycle of the clock signal can affect the performance of the A/D Converter. Because achieving a precise duty cycle is difficult, the ADC12020 is designed to maintain performance over a range of duty cycles. While it is specified and performance is guaranteed with a 50% clock duty cycle, performance is typically maintained over a clock duty cycle range of 20% to 80%.

The clock line should be series terminated at the source end in the characteristic impedance of that line if it is longer than

where t_r is the rise time of the clock signal and t_{PR} is the propagation rate down the line. For a Board of FR-4 material, t_{PR} is typically about 150 ps/inch, or 60 ps/cm. This resistor should be as close to the source as possible.

It might also be necessary to AC terminate the ADC end of the clock line with a series RC to ground such that the resistor value equals the characteristic impedance of the clock line and the capacitor value is

$$C \geq \frac{4 \times t_{PR} \times L}{Z_{O}}$$

where t_{PR} is again the propagation rate down the clock line, L is the length of the line in inches and Z_{O} is the characteristic impedance of the clock line. A.C. termination should be near the ADC clock pin but beyond that pin as seen from the clock source.

Take care to maintain a constant clock line impedance throughout the length of the line. Refer to Application Note AN-905 or AN-1113 for information on setting characteristic impedance.

2.2 OE

The $\overline{\text{OE}}$ pin, when high, puts the output pins into a high impedance state. When this pin is low the outputs are in the active state. The ADC12020 will continue to convert whether this pin is high or low, but the output can not be read while the $\overline{\text{OE}}$ pin is high.

The $\overline{\text{OE}}$ pin should NOT be used to multiplex devices together to drive a common bus as this will result in excessive capacitance on the data output pins, reducing SNR and SINAD performance of the converter. See Section 3.0.

2.3 PD

The PD pin, when high, holds the ADC12020 in a powerdown mode to conserve power when the converter is not being used. The power consumption 40 mW and the output data pins are undefined in this mode. The data in the pipeline is corrupted while in the power down mode.

The Power Down Mode Exit Cycle time is determined by the value of the capacitors on pins 30, 31 and 32. These capacitors loose their charge in the Power Down mode and must be charged by on-chip circuitry before conversions can be accurate.

3.0 OUTPUTS

The ADC12020 has 12 TTL/CMOS compatible Data Output pins. Valid offset binary data is present at these outputs while

the \overline{OE} and PD pins are low. While the t_{OD} time provides information about output timing, a simple way to capture a valid output is to latch the data on the falling edge of the conversion clock (pin 10).

Be very careful when driving a high capacitance bus. The more capacitance the output drivers must charge for each conversion, the more instantaneous digital current flows through $V_{\rm DR}$ and DR GND. These large charging current spikes can cause on-chip noise that can couple into the analog circuitry, degrading dynamic performance. Adequate power supply bypassing and careful attention to the ground plane will reduce this problem. Additionally, bus capacitance beyond the specified 25 pF/pin will cause $t_{\rm OD}$ to increase, making it difficult to properly latch the ADC output data. The result could be an apparent reduction in dynamic performance.

To minimize noise due to output switching, minimize the load currents at the digital outputs. This can be done by connecting buffers (74ACQ541, for example) between the ADC outputs and any other circuitry. Only one driven input should be connected to each output pin. Additionally, inserting series resistors of 47Ω to 100Ω at the digital outputs, close to the ADC pins, will isolate the outputs from trace and other circuit capacitances and limit the output currents, which could otherwise result in performance degradation. See *Figure 4*.

While the ADC12010 will operate with V_{DR} voltages down to 1.8V, t_{OD} increases with reduced V_{DR} . Be careful of external timing when using reduced V_{DR} .

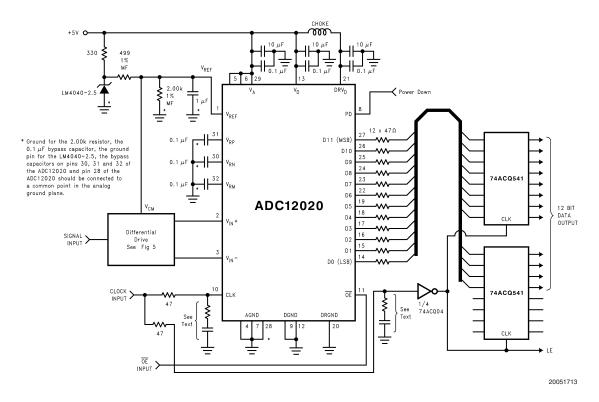
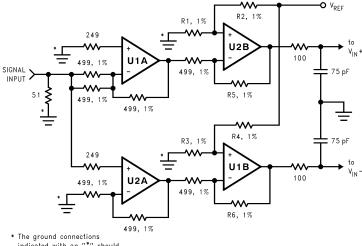


FIGURE 4. Simple Application Circuit with Single-Ended to Differential Buffer



* The ground connections indicated with an "*" should be connected to a common point in the analog ground plane.

Amplifiers: two LM6628s

20051714

FIGURE 5. Differential Drive Circuit of Figure 4

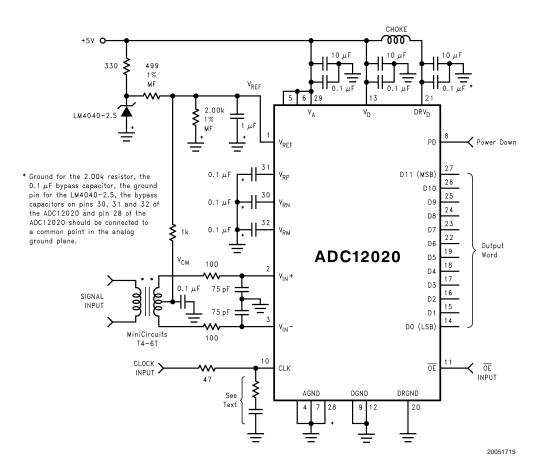


FIGURE 6. Driving the Signal Inputs with a Transformer

4.0 POWER SUPPLY CONSIDERATIONS

The power supply pins should be bypassed with a 10 μ F capacitor and with a 0.1 μ F ceramic chip capacitor within a centimeter of each power pin. Leadless chip capacitors are preferred because they have low series inductance.

As is the case with all high-speed converters, the ADC12020 is sensitive to power supply noise. Accordingly, the noise on the analog supply pin should be kept below 100 mV_{P-P}.

No pin should ever have a voltage on it that is in excess of the supply voltages, not even on a transient basis. Be especially careful of this during turn on and turn off of power.

The V_{DR} pin provides power for the output drivers and may be operated from a supply in the range of 2.35V to V_D (nominal 5V). This can simplify interfacing to 3V devices and systems. **DO NOT operate the V_{DR} pin at a voltage higher than V_D.**

5.0 LAYOUT AND GROUNDING

Proper grounding and proper routing of all signals are essential to ensure accurate conversion. Maintaining separate analog and digital areas of the board, with the ADC12020 between these areas, is required to achieve specified performance.

The ground return for the data outputs (DR GND) carries the ground current for the output drivers. The output current can exhibit high transients that could add noise to the conversion process. To prevent this from happening, the DR GND pins should NOT be connected to system ground in close proximity to any of the ADC12020's other ground pins.

Capacitive coupling between the typically noisy digital circuitry and the sensitive analog circuitry can lead to poor performance. The solution is to keep the analog circuitry separated from the digital circuitry, and to keep the clock line as short as possible.

Digital circuits create substantial supply and ground current transients. The logic noise thus generated could have significant impact upon system noise performance. The best logic family to use in systems with A/D converters is one which employs non-saturating transistor designs, or has low noise characteristics, such as the 74LS, 74HC(T) and 74AC(T)Q families. The worst noise generators are logic families that draw the largest supply current transients during clock or signal edges, like the 74F and the 74AC(T) families.

The effects of the noise generated from the ADC output switching can be minimized through the use of 47Ω to 100Ω resistors in series with each data output line. Locate these resistors as close to the ADC output pins as possible.

Since digital switching transients are composed largely of high frequency components, total ground plane copper weight will have little effect upon the logic-generated noise. This is because of the skin effect. Total surface area is more important than is total ground plane volume.

Generally, analog and digital lines should cross each other at 90° to avoid crosstalk. To maximize accuracy in high speed, high resolution systems, however, avoid crossing analog and digital lines altogether. It is important to keep clock lines as short as possible and isolated from ALL other lines, including other digital lines. Even the generally accepted 90° crossing should be avoided with the clock line as even a little coupling can cause problems at high frequencies. This is because other lines can introduce jitter into the clock line, which can lead to degradation of SNR. Also, the high speed clock can introduce noise into the analog chain.

Best performance at high frequencies and at high resolution is obtained with a straight signal path. That is, the signal path through all components should form a straight line wherever possible.

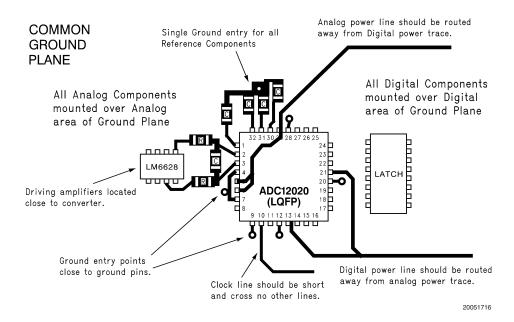


FIGURE 7. Example of a Suitable Layout

Be especially careful with the layout of inductors. Mutual inductance can change the characteristics of the circuit in which they are used. Inductors should *not* be placed side by side, even with just a small part of their bodies beside each other.

The analog input should be isolated from noisy signal traces to avoid coupling of spurious signals into the input. Any external component (e.g., a filter capacitor) connected between the converter's input pins and ground or to the reference input pin and ground should be connected to a very clean point in the analog ground plane.

Figure 7 gives an example of a suitable layout. All analog circuitry (input amplifiers, filters, reference components, etc.) should be placed over the analog ground plane. All digital circuitry and I/O lines should be placed in the digital area of the board. Furthermore, all components in the reference circuitry and the input signal chain that are connected to ground should be connected together with short traces and enter the ground plane at a single point. All ground connections should have a low inductance path to ground.

We do not recommend a split ground plane. Rather, using wide power traces with analog and digital power traces well-separated from each other, and keeping analog and digital signal lines well-separated from each other will minimize noise while keeping EMI to tolerable levels.

6.0 DYNAMIC PERFORMANCE

To achieve the best dynamic performance, the clock source driving the CLK input must be free of jitter. Isolate the ADC clock from any digital circuitry with buffers, as with the clock tree shown in *Figure 8*.

As mentioned in Section 5.0, it is good practice to keep the ADC clock line as short as possible and to keep it well away from any other signals. Other signals can introduce jitter into the clock signal, which can lead to reduced SNR performance, and the clock can introduce noise into other lines. Even lines with 90° crossings have capacitive coupling, so try to avoid even these 90° crossings of the clock line.

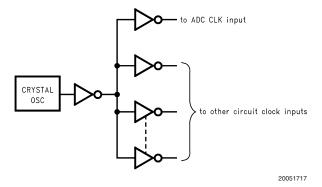


FIGURE 8. Isolating the ADC Clock from other Circuitry with a Clock Tree

7.0 COMMON APPLICATION PITFALLS

Driving the inputs (analog or digital) beyond the power supply rails. For proper operation, all inputs should not go more than 100 mV beyond the supply rails (more than 100 mV below the ground pins or 100 mV above the supply

pins). Exceeding these limits on even a transient basis may cause faulty or erratic operation. It is not uncommon for high speed digital components (e.g., 74F and 74AC devices) to exhibit overshoot or undershoot that goes above the power supply or below ground. A resistor of about 50Ω to 100Ω in series with any offending digital input, close to the signal source, will eliminate the problem.

Do not allow input voltages to exceed the supply voltage, even on a transient basis. Not even during power up or power down.

Be careful not to overdrive the inputs of the ADC12020 with a device that is powered from supplies outside the range of the ADC12020 supply. Such practice may lead to conversion inaccuracies and even to device damage.

Attempting to drive a high capacitance digital data bus.

The more capacitance the output drivers must charge for each conversion, the more instantaneous digital current flows through $V_{\rm DR}$ and DR GND. These large charging current spikes can couple into the analog circuitry, degrading dynamic performance. Adequate bypassing and maintaining separate analog and digital areas on the pc board will reduce this problem.

Additionally, bus capacitance beyond the specified 25 pF/pin will cause $t_{\rm OD}$ to increase, making it difficult to properly latch the ADC output data. The result could, again, be an apparent reduction in dynamic performance.

The digital data outputs should be buffered (with 74ACQ541, for example). Dynamic performance can also be improved by adding series resistors at each digital output, close to the ADC12020, which reduces the energy coupled back into the converter output pins by limiting the output current. A reasonable value for these resistors is 47Ω to 100Ω .

Using an inadequate amplifier to drive the analog input. As explained in Section 1.3, the capacitance seen at the input alternates between 8 pF and 7 pF, depending upon the phase of the clock. This dynamic load is more difficult to drive than is a fixed capacitance.

If the amplifier exhibits overshoot, ringing, or any evidence of instability, even at a very low level, it will degrade performance. A small series resistor and shunt capacitor at each amplifier output (as shown in *Figure 5*)will improve performance. The LMH6702 and the LMH6628 have been successfully used to drive the analog inputs of the ADC12020.

Also, it is important that the signals at the two inputs have exactly the same amplitude and be exactly 180° out of phase with each other. Board layout, especially equality of the length of the two traces to the input pins, will affect the effective phase between these two signals. Remember that an operational amplifier operated in the non-inverting configuration will exhibit more time delay than will the same device operating in the inverting configuration.

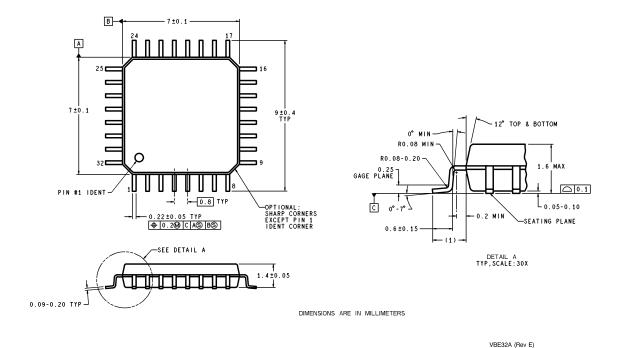
Operating with the reference pins outside of the specified range. As mentioned in Section 1.2, $V_{\rm REF}$ should be in the range of

$$1.0V \le V_{REF} \le 2.4V$$

Operating outside of these limits could lead to performance degradation.

Using a clock source with excessive jitter, using excessively long clock signal trace, or having other signals coupled to the clock signal trace. This will cause the sampling interval to vary, causing excessive output noise and a reduction in SNR and SINAD performance.

Physical Dimensions inches (millimeters) unless otherwise noted



32-Lead LQFP Package Ordering Number ADC12020CIVY **NS Package Number VBE32A**

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF THE PRESIDENT AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, and whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in a significant injury to the user.
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



National Semiconductor Americas Customer Support Center Email: new.feedback@nsc.com

Tel: 1-800-272-9959

www.national.com

National Semiconductor Europe Customer Support Center

Fax: +49 (0) 180-530 85 86 Email: europe.support@nsc.com Deutsch Tel: +49 (0) 69 9508 6208 English Tel: +44 (0) 870 24 0 2171

Français Tel: +33 (0) 1 41 91 8790

National Semiconductor Support Center Email: ap.support@nsc.com **National Semiconductor** Japan Customer Support Center Fax: 81-3-5639-7507 Email: jpn.feedback@nsc.com Tel: 81-3-5639-7560